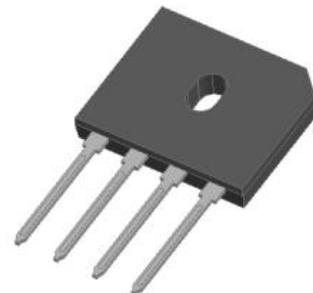
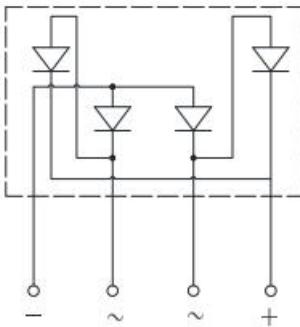


Bridge Rectifier Diode 整流桥**■Features 特点**

Glass passivated chip junction 玻璃钝化结
 High surge current capability 高浪涌电流能力
 Ideal for PCB 适用于印刷电路板
 Solder dip 275°C 7S 焊接 275 度 7 秒内
 Package 封装: GBU

**■Maximum Rating 最大额定值**(T_A=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数 | Symbol 符号 | GBU1005 | GBU1001 | GBU1002 | GBU1004 | GBU1006 | GBU1008 | GBU1010 | Unit 单位 |
|--|-----------------------------------|---------|---------|---------|----------------------|---------|---------|---------|---------|
| Peak Reverse Voltage 反向峰值电压 | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| DC Reverse Voltage 直流反向电压 | V _{R(DC)} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage 反向电压均方根值 | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Forward Rectified Current 正向整流电流 | I _F | | | | 10 | | | | A |
| Peak Surge Current 峰值浪涌电流 | I _{FSM} | | | | 200 | | | | A |
| Thermal Resistance J-A 结到环境热阻 | R _{θJA} | | | | 25 | | | | °C/W |
| Junction and Storage Temperature 结温和储藏温度 | T _J , T _{stg} | | | | 150°C, -55 to +150°C | | | | |

■Electrical Characteristics 电特性(T_A=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数 | Symbol 符号 | Min 最小值 | Typ 典型值 | Max 最大值 | Unit 单位 | Condition 条件 |
|---|----------------|---------|---------|----------|---------|----------------------------------|
| Forward Voltage 正向电压 | V _F | | 1.1 | | V | I _F =5A |
| Reverse Current (T _A =25°C) 反向电流(T _A =100°C) | I _R | | | 5 500 | uA | V _R =V _{RRM} |
| Diode Capacitance 二极管电容 | C _D | | 25 | | pF | V _R =4V, f=1MHz |

■Typical Characteristic Curve 典型特性曲线

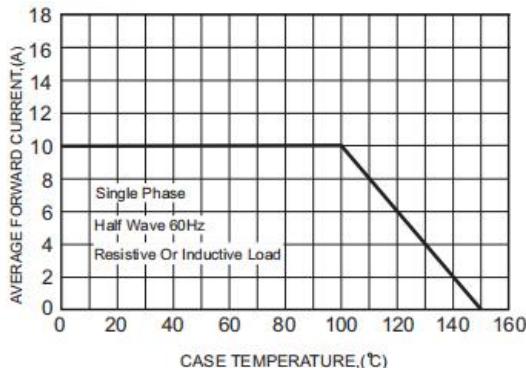


Figure 1: Forward Current Derating Curve

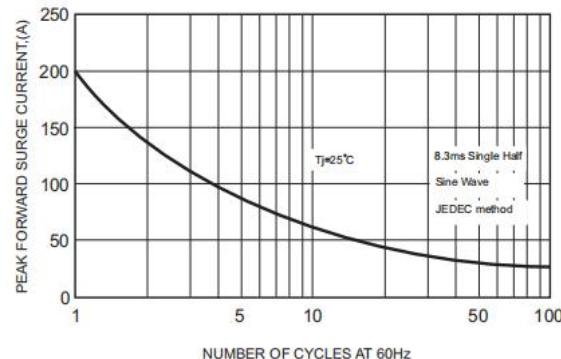


Figure 2: Peak Forward Surge Current

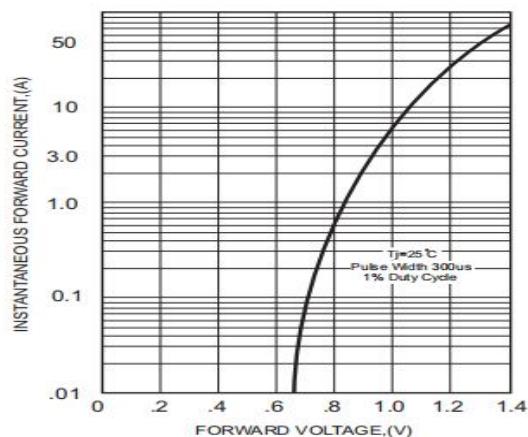


Figure 3: Instantaneous Forward Characteristics

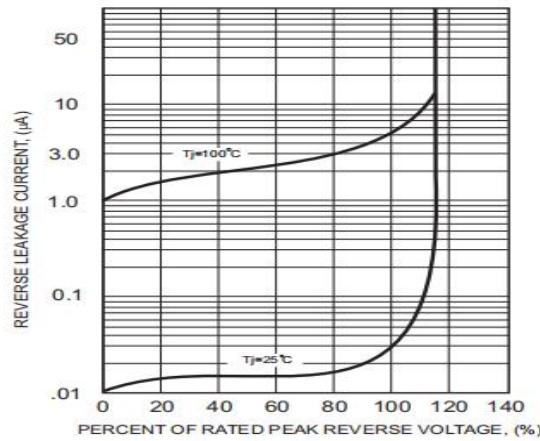
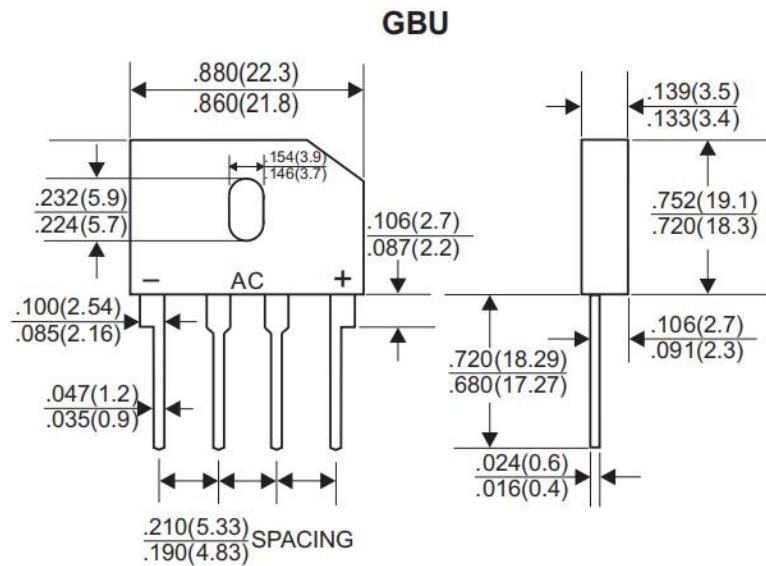


Figure 4: Reverse Leakage Characteristics

■Dimension 外形封装尺寸



Dimensions in inches and (millimeters)